NSN 5961-01-079-0425



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-079-0425 **Inclosure Material:** Metal **Overall Length:** 0.935 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-60 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 4.0 small-signal short-circuit forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 3 uninsulated wire lead Shelf Life: N/a

Unit Of Measure:

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Demilitarization:

No

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